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Introduction

In 2015, the 23rd SPIE Conference on Physics and Simulation of Optoelectronic Devices was held at the Photonics West symposium in San Francisco. The scope of this well-established conference was to unveil and study the physical principles of optoelectronic materials, devices, and systems with the help of theory and simulation.

With 11 invited, 43 contributed talks and 19 posters, the conference presented latest findings in fields such as plasmonics, quantum optics, nonlinear optical phenomena and their applications in lasers, detectors, light-emitting diodes and solar cells. For attendees of Photonics West, it complemented the conferences with experimental and technology focus in a seamless fashion.

The Physics and Simulation of Optoelectronic Devices conference has had a successful history due to the highly valuable contributions of the program committee and the organizational team. With great sadness we would like to report that our co-chair Prof. Dr. Fritz Henneberger passed away just before the 2015 conference. He was a pillar of strength in the conference as a part of the program committee since 1997, and with his move to the co-chair position in 2004. As an author, he was active since 1991. He organized and proposed many special sessions with highest quality contributions, identified novel topics to bring into the conference, and hence made a lasting impact which we will remember for a long time.

Bernd Witzigmann Marek Osiński Yasuhiko Arakawa

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